

RGTH80TK65

650V 40A Field Stop Trench IGBT

V _{CES}	650V
I _{C(100°C)}	19A
V _{CE(sat) (Typ.)}	1.6V@I _C =40A
P_D	66W

P_D ●Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

PFC

UPS

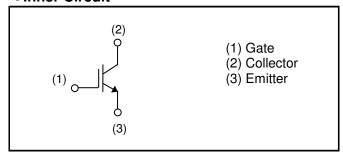
Power Conditioner

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Type	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTH80TK65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit	
Collector - Emitter Voltage		V _{CES}	650	V	
Gate - Emitter Voltage		V _{GES}	±30	V	
Collector Current	T _C = 25°C	I _C	31	Α	
	$T_C = 100$ °C	I _C	19	Α	
Pulsed Collector Current		I _{CP} *1	160	А	
Power Dissipation	T _C = 25°C	P _D	66	W	
	$T_C = 100$ °C	P _D	33	W	
Operating Junction Temperature		T _j	-40 to +175	°C	
Storage Temperature		T _{stg}	-55 to +175	°C	

^{*1} Pulse width limited by T_{jmax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
Farameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	ı	2.27	°C/W

ullet IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol		Min.	Тур.	Max.	Uniit
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	1	1	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	ı	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	ı	1	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 27.6 \text{mA}$	4.5	5.5	6.5	٧
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_C = 40A$, $V_{GE} = 15V$ $T_j = 25$ °C $T_j = 175$ °C	-	1.6 2.1	2.1 -	V

ullet IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Darameter	Symbol	Conditions	Values			I India
Parameter			Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V	-	2210	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$	-	85	-	рF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	35	-	
Total Gate Charge	Q_g	V _{CE} = 300V	-	79	-	
Gate - Emitter Charge	Q_{ge}	I _C = 40A	-	21	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	29	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 40A, V_{CC} = 400V$	-	34	-	
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	50	-	20
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	120	-	ns
Fall Time	t _f	Inductive Load	-	47	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 40A, V_{CC} = 400V$	-	34	-	
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	50	-	no
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	135	-	ns
Fall Time	t _f	Inductive Load	-	59	-	
		$I_C = 160A, V_{CC} = 520V$				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650 V, V_{GE} = 15 V$	FU	FULL SQUARE		
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

Fig.1 Power Dissipation vs. Case Temperature

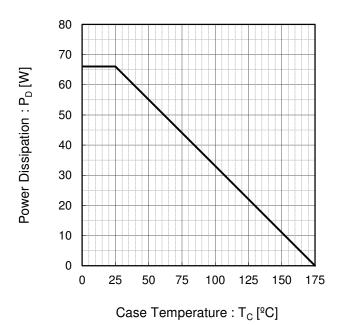


Fig.2 Collector Current vs. Case Temperature

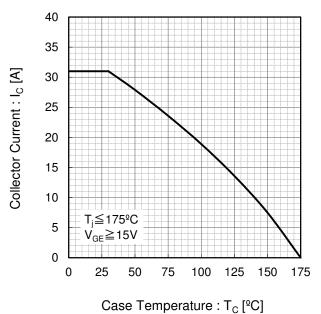


Fig.3 Forward Bias Safe Operating Area

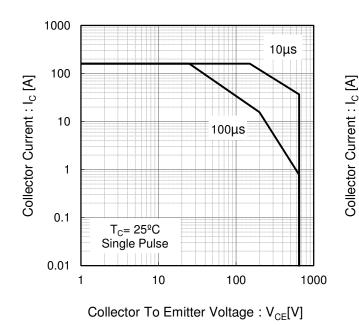
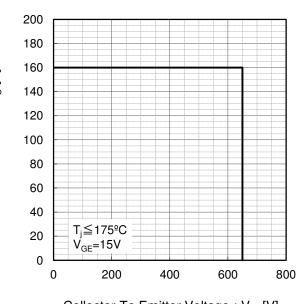


Fig.4 Reverse Bias Safe Operating Area



Collector To Emitter Voltage : $V_{CE}[V]$

Fig.5 Typical Output Characteristics

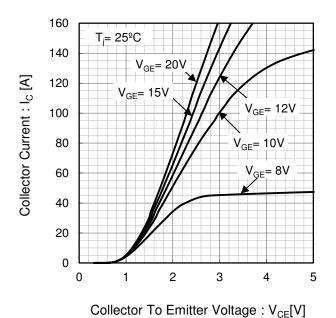
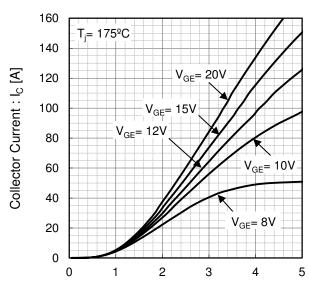


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage: V_{CE}[V]

Fig.7 Typical Transfer Characteristics

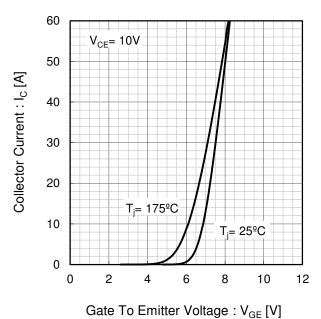


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

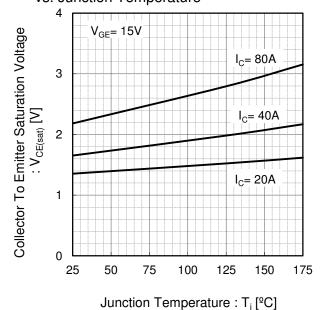
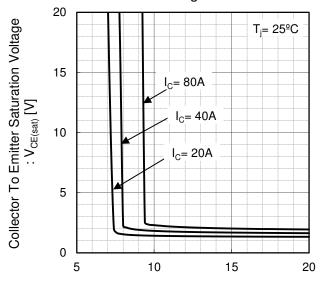
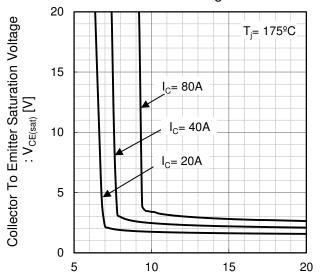


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage: V_{GE} [V]

Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage: V_{GE} [V]

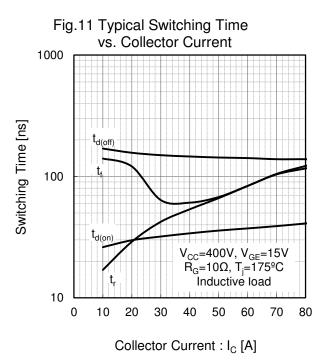


Fig.12 Typical Switching Time vs. Gate Resistance 1000 Switching Time [ns] $t_{d(off)}$ 100 V_{CC} =400V, I_{C} =40A V_{GE} =15V, T_{j} =175 $^{\circ}$ C $t_{d(on)}$ Inductive load 10 10 0 20 30 40 50 Gate Resistance : $R_G[\Omega]$

Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 Eoff Eor 0.1 V_{CC} =400V, V_{GE} =15V R_{G} =10 Ω , T_{j} =175 o C Înductive load 0.01 50 70 0 20 30 40 60 80 10 Collector Current : I_C [A]

Fig.14 Typical Switching Energy Losses vs. Gate Resistance 10 Switching Energy Losses [mJ] $\mathsf{E}_{\mathsf{off}}$ 1 Eon 0.1 V_{CC} =400V, I_{C} =40A V_{GE} =15V, T_{j} =175 $^{\circ}$ C Inductive load 0.01 0 10 20 30 40 50 Gate Resistance : $R_G[\Omega]$

Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 Cres 10 f=1MHz $V_{GE}=0V$ T_i=25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage: V_{CE}[V]

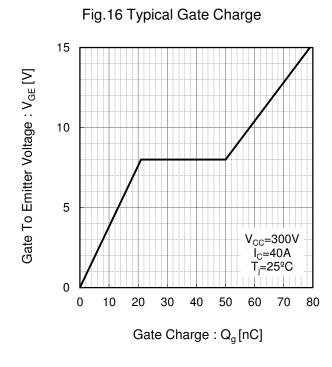
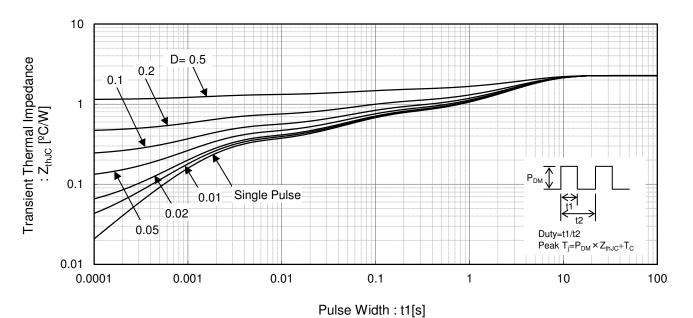


Fig.17 IGBT Transient Thermal Impedance



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●Inductive Load Switching Circuit and Waveform

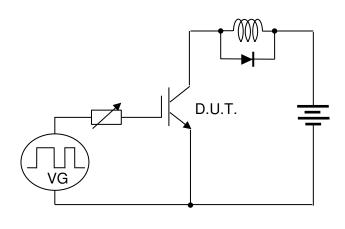


Fig.18 Inductive Load Circuit

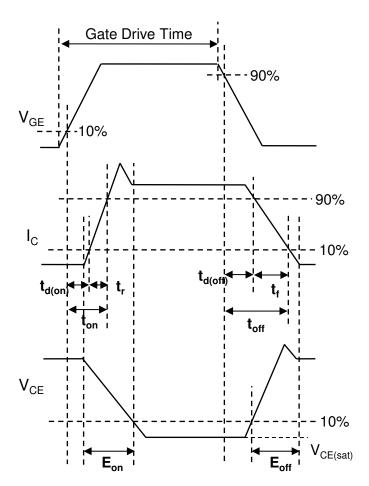


Fig.19 Inductive Load Waveform

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